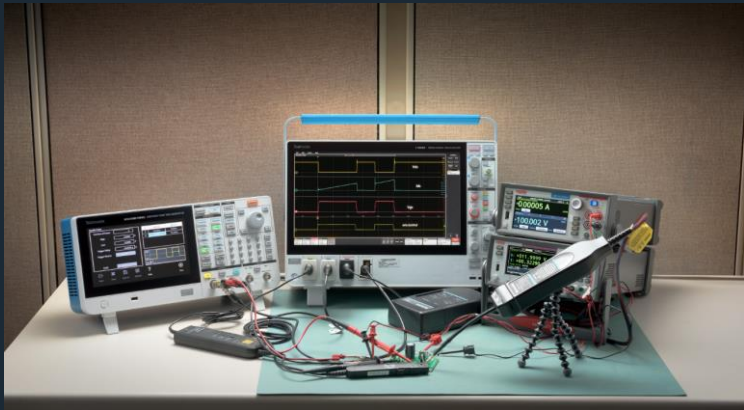


Tektronix and CN Rood Presents

The Standard Method for Measuring Switching Parameters

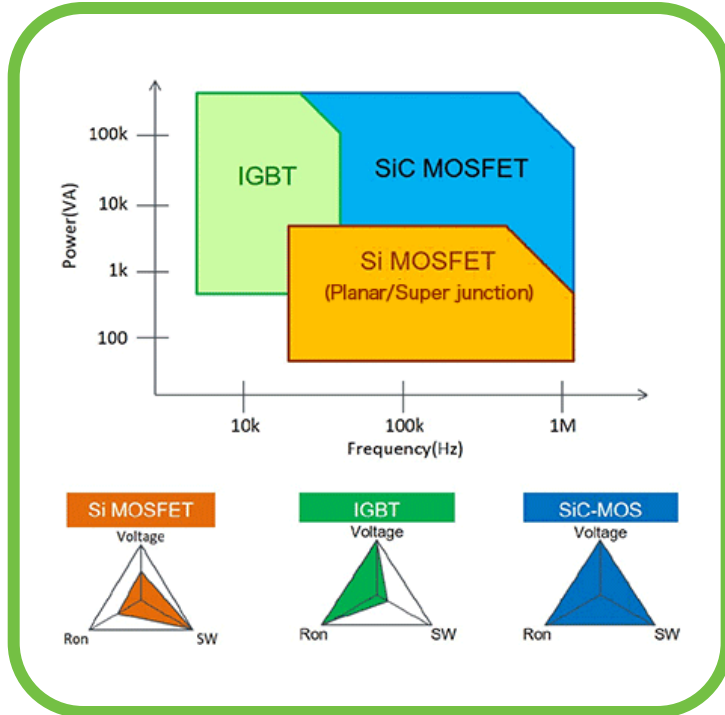


E&A
ELECTRONICS'23
& APPLICATIONS

Agenda

- Why Wide Bandgap (WBG) ?
- What is Double pulse test
 - *Principle and Key measurements*
- Measurement Challenges
 - *Gate driving Stimulus, Probing (Low /High Side) , Deskew*
- Questions

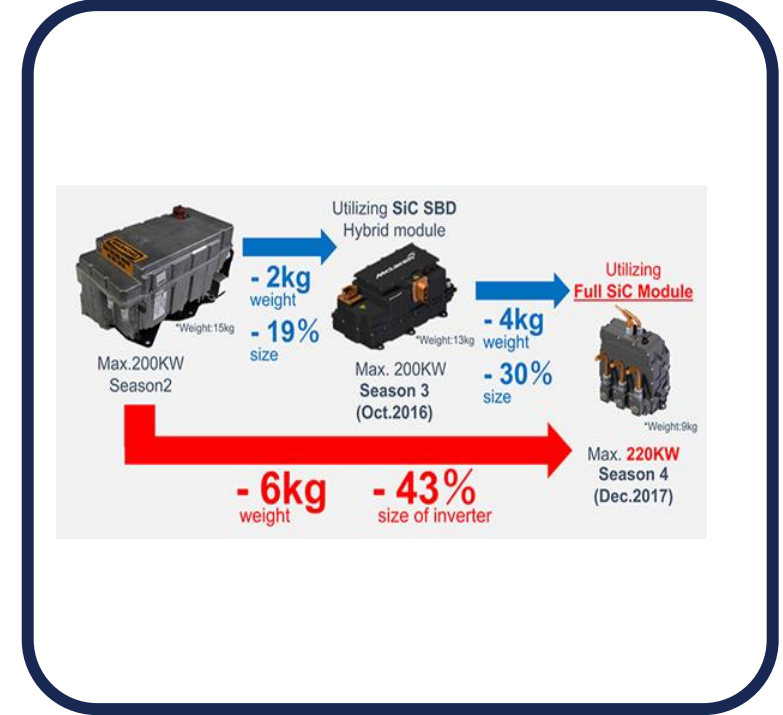
Why Wide Bandgap?



Higher Power Levels
Faster Switching speeds



Lower Switching Losses

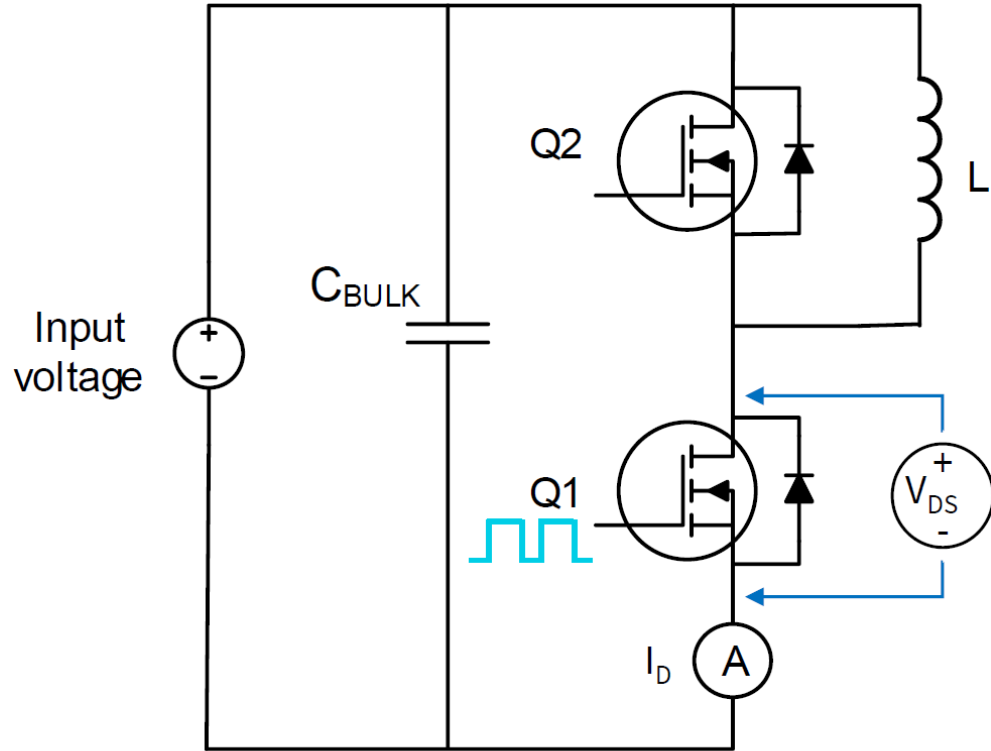


Smaller Form Factor

What is a Double Pulse Test?

What is Double pulse test (DPT) ?

DEFINITION



Double-Pulse Test Circuit

Evaluate and optimize the switching performance of power MOSFETs or IGBT

Why?

- Gate drive optimization
- Calculating switching losses in the final design

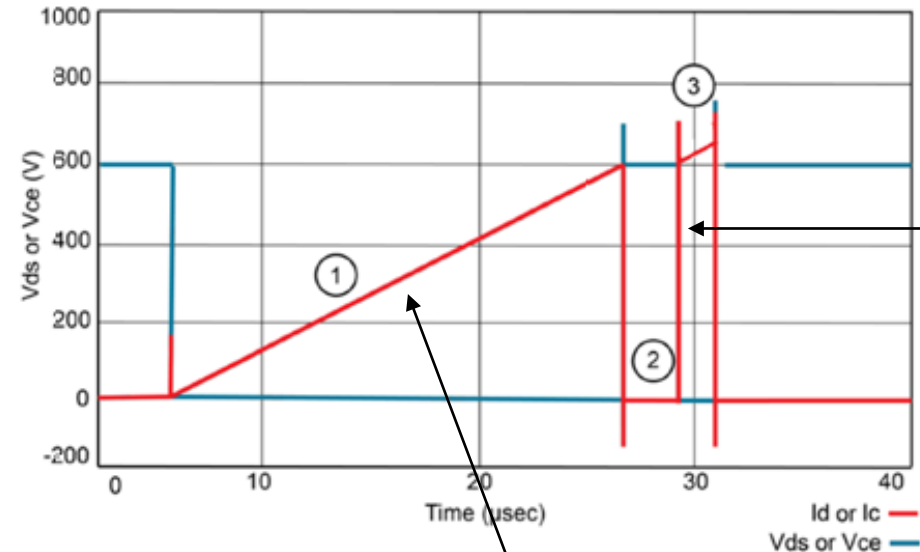
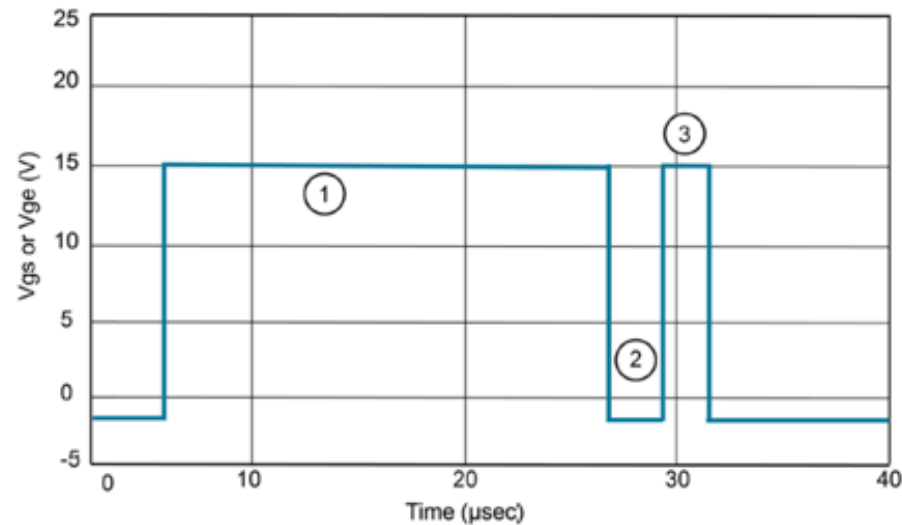
Dynamic performance evaluation over the full range of operating conditions

- Timing (T_{don} , T_{doff} , T_{rise} , T_{fall} ...)
- Amplitude (overshoot, ringing...)
- Speed (dI/dt , dV/dt ...)
- Switching energy (E_{on} , E_{off} , E_{err} ...)

What is Double pulse test (DPT) ?

DEFINITION

Q1 gate is driven with a controlled double pulse pattern, while Q2 is off



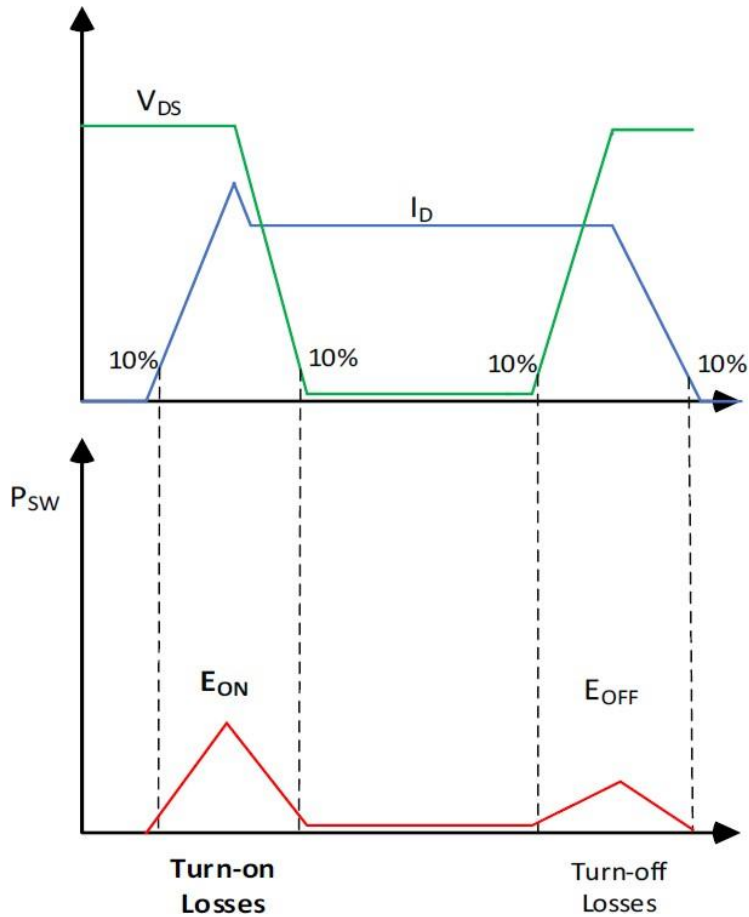
Second pulse is where the parameters are measured

During the 1st pulse the current builds through the inductor

$$I_{max} = \frac{V \cdot \Delta t}{L}$$

What is Double pulse test (DPT) ?

KEY MEASUREMENTS: EON, EOFF

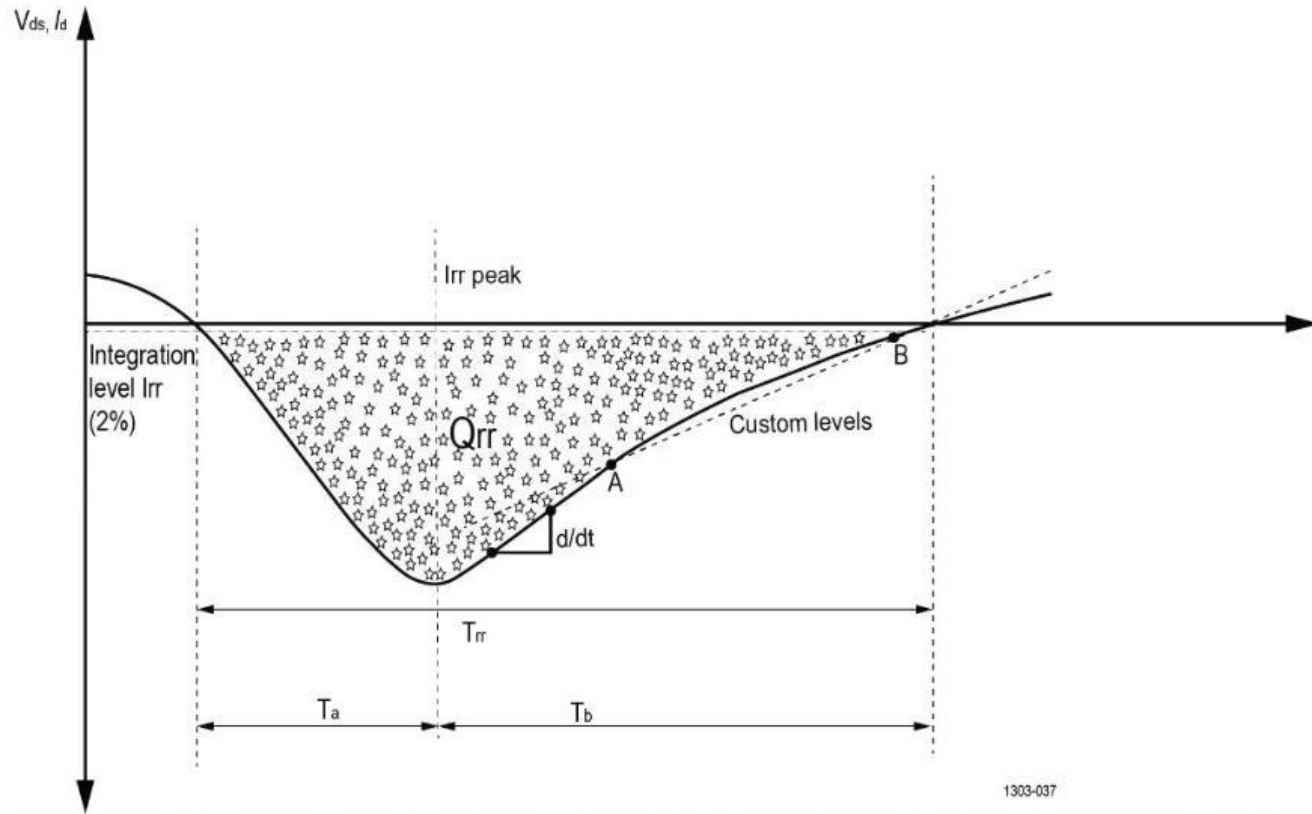


$$E_{on} = \int_{10\% I_{ds}}^{10\% V_{ds}} V_{DS} \times I_{DS}$$

$$E_{off} = \int_{10\% V_{ds}}^{10\% I_{ds}} V_{DS} \times I_{DS}$$

What is Double pulse test (DPT) ?

KEY MEASUREMENTS: REVERSE RECOVERY



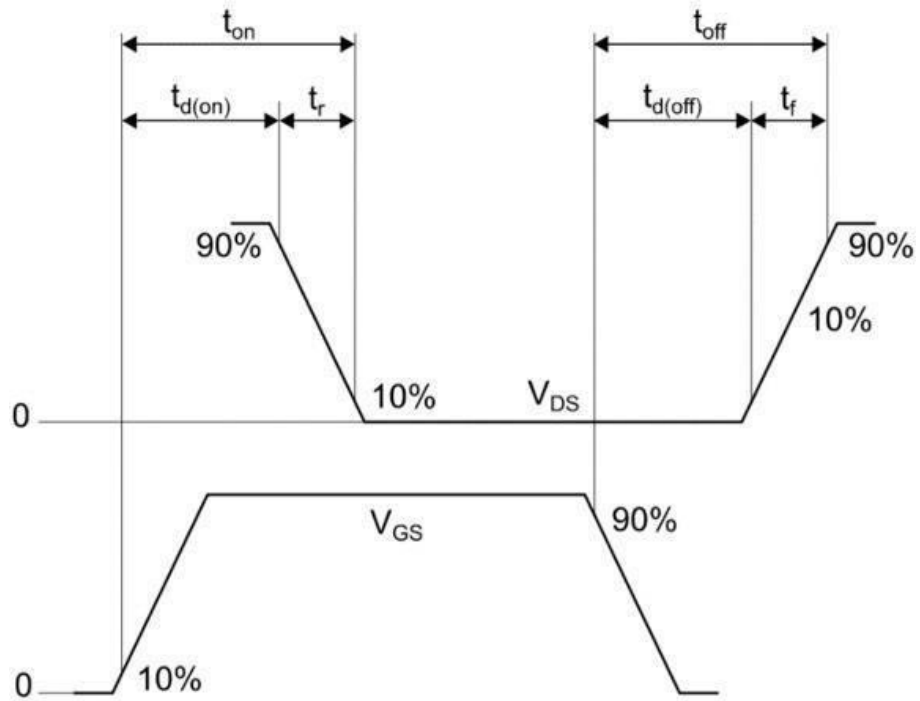
$$Q_{rr} = \int_{t_0}^{t_0+t_i} I_{rr} \times dt$$

$$Err = \int_{t_0}^{t_0+t_i} V_R \times I_{rr} \times dt$$

1303-037

What is Double pulse test (DPT) ?

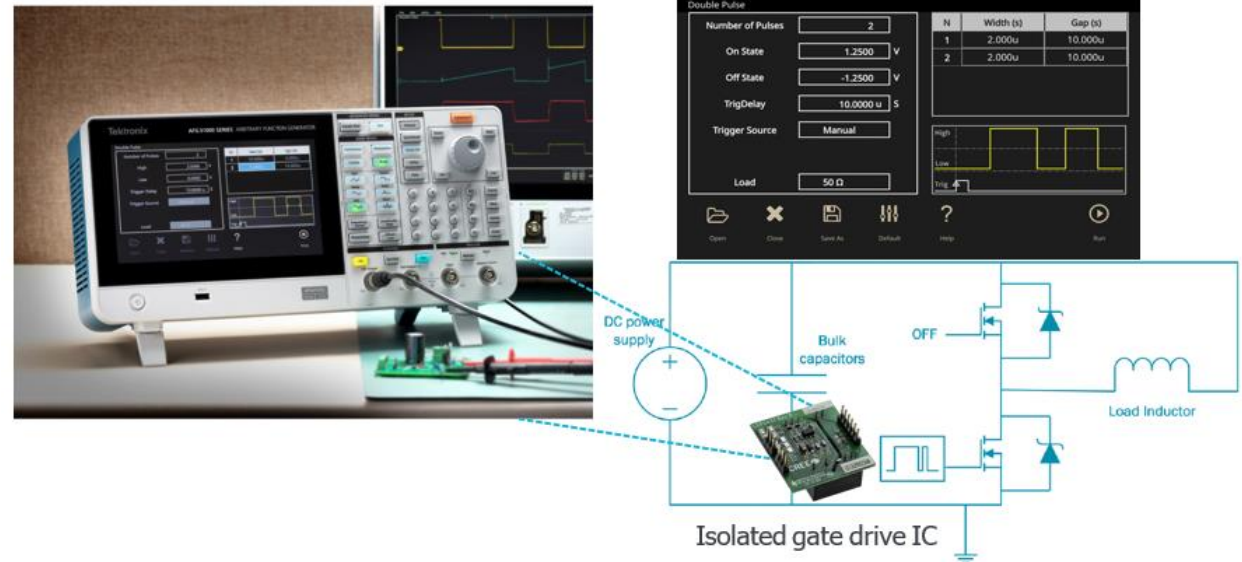
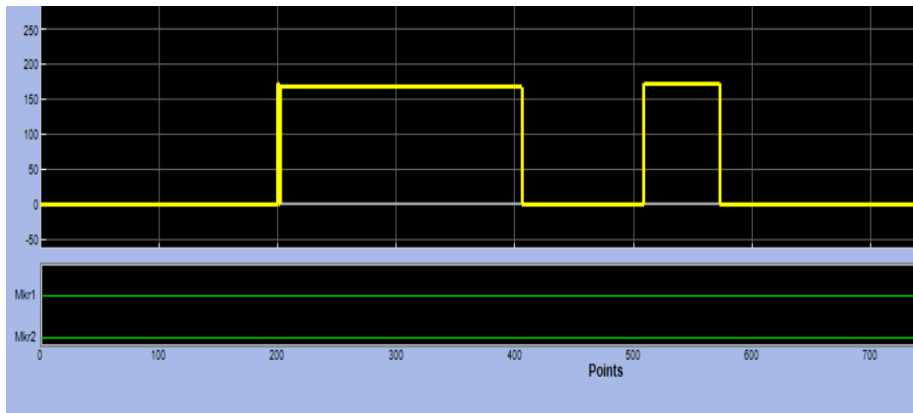
KEY MEASUREMENTS: TIMING



Measurement Challenges

How to drive the gate?

- Traditional function generator cannot control each pulse width individually
- Using PC to create arbitrary waveforms and load them onto the AFG is cumbersome and time consuming
- Using uC requires the user to write code. Off the shelf solutions lack flexibility



The importance of probing



The importance of probing

BANDWIDTH

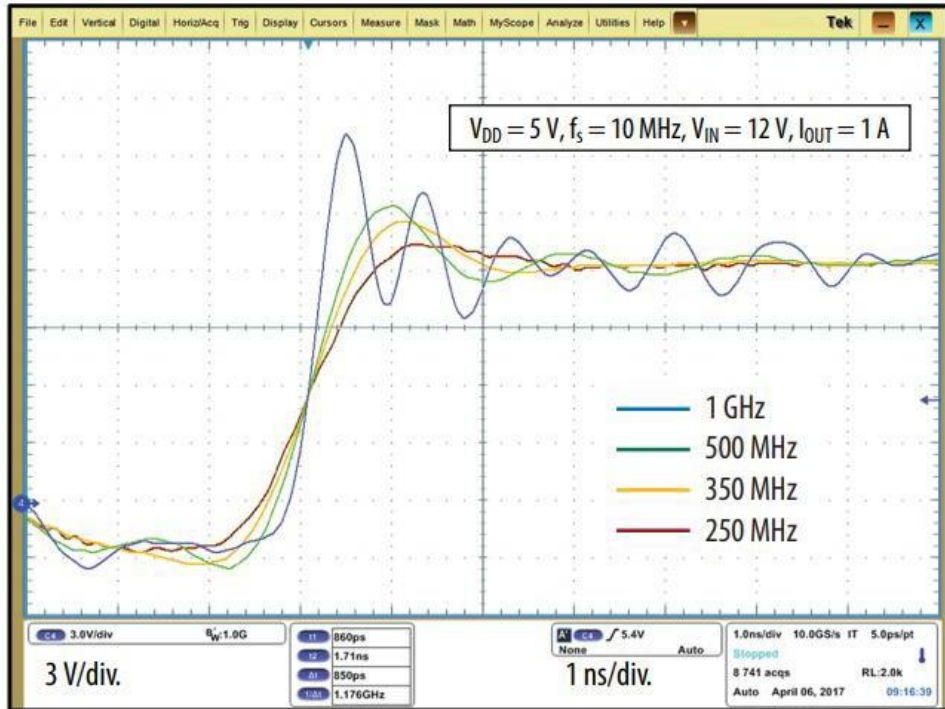


Figure 3: Effect of probe/system bandwidth on captured waveform (EPC8009 based board).

$$t_{r(\text{probe})} = \frac{0.3 \dots 0.4}{BW}$$

$$t_{r(\text{measured})} = \sqrt{t_{r(\text{signal})}^2 + t_{r(\text{probe})}^2}$$

For reasonable accuracy, $t_{r(\text{probe})} \approx 5 * t_{r(\text{signal})}$

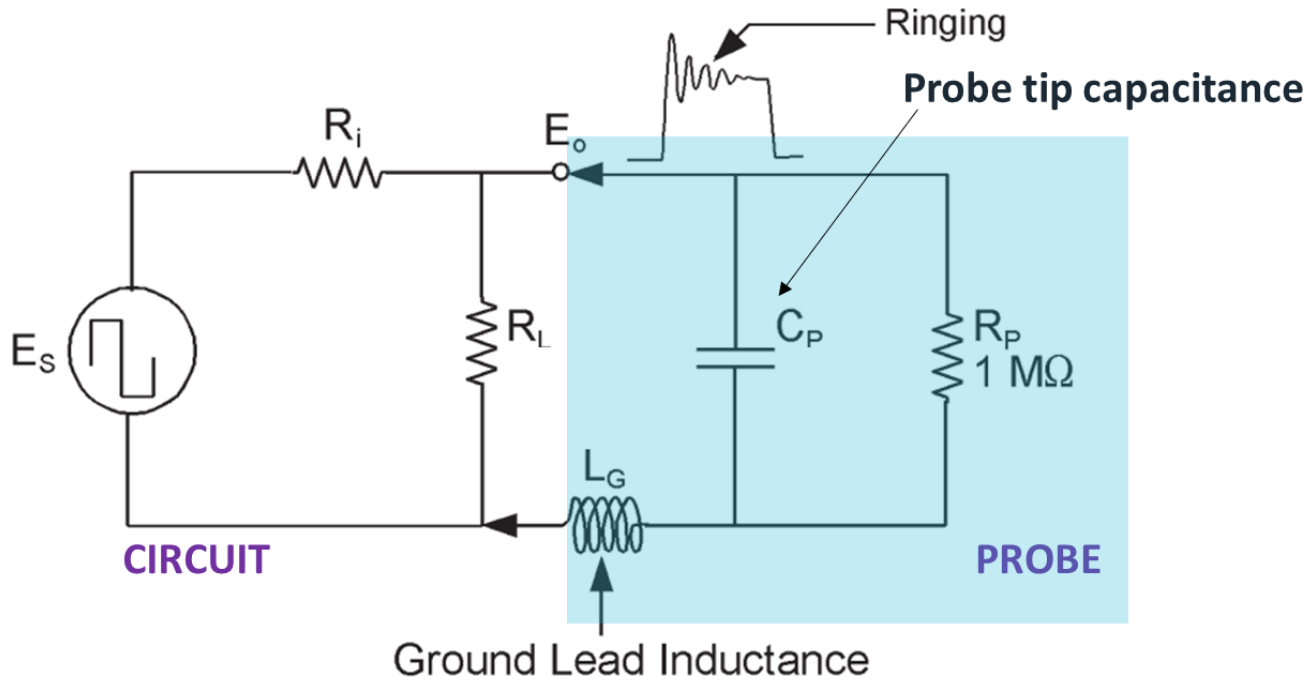
PE29100 High-speed FET Driver

Table 3 • DC Characteristics (Cont.)

Parameter	Condition	Typ	Unit
Dead-time control voltages	30k to 80 kΩ resistor to GND	1.2	V
Dead-time from HSG going low to LSG going high	RDHL = 30 kΩ	0.8	ns
	RDHL = 80 kΩ	3.4	ns
Dead-time from LSG going low to HSG going high	RDLH = 30 kΩ	0.8	ns
	RDLH = 80 kΩ	3.2	ns
Switching Characteristics			
LSG turn-off propagation delay	At min dead time	8.4	ns
HSG rise time	10%–90%	1.0	ns
	10%–90% with 1000 pF load	2.5	
LSG rise time	10%–90%	1.0	ns
	10%–90% with 1000 pF load	1.8	
HSG fall time	10%–90%	0.9	ns
	10%–90% with 1000 pF load	2.5	
LSG fall time	10%–90%	0.9	ns
	10%–90% with 1000 pF load	1.8	
Max switching frequency @ 50% duty cycle	RDHL = RDLH = 80 kΩ	33	MHz

The importance of probing

PARASITIC CAPACITANCE



- Decrease amplitude
- Change phase
- Slow down rise time
 $tr = 2.2 * R_{source} * C_p$

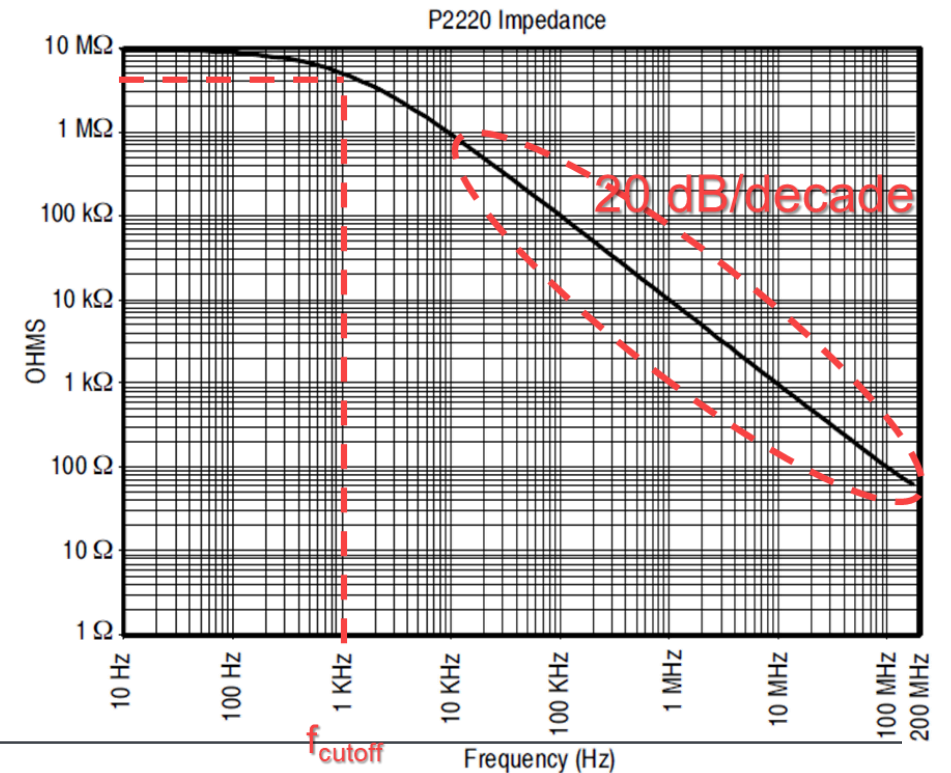
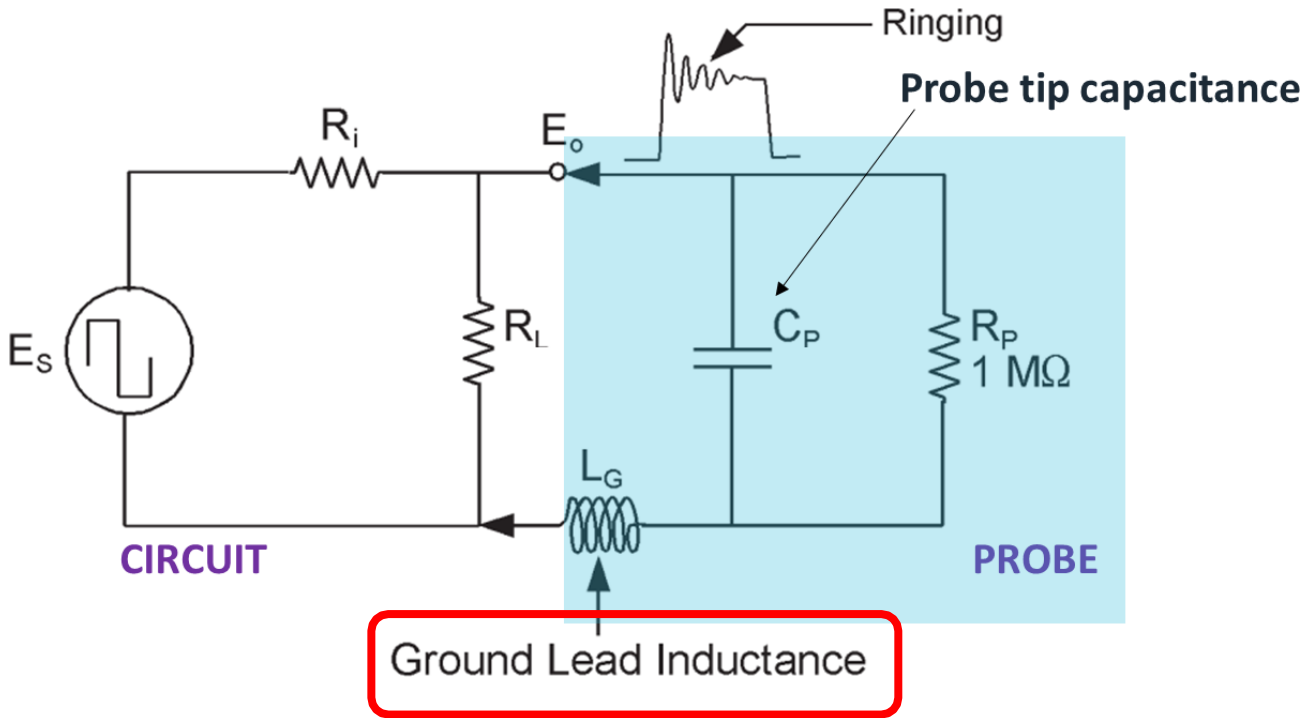


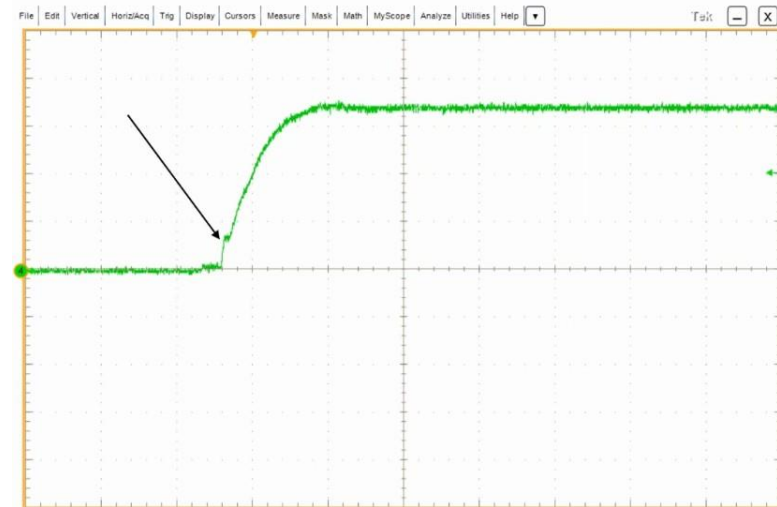
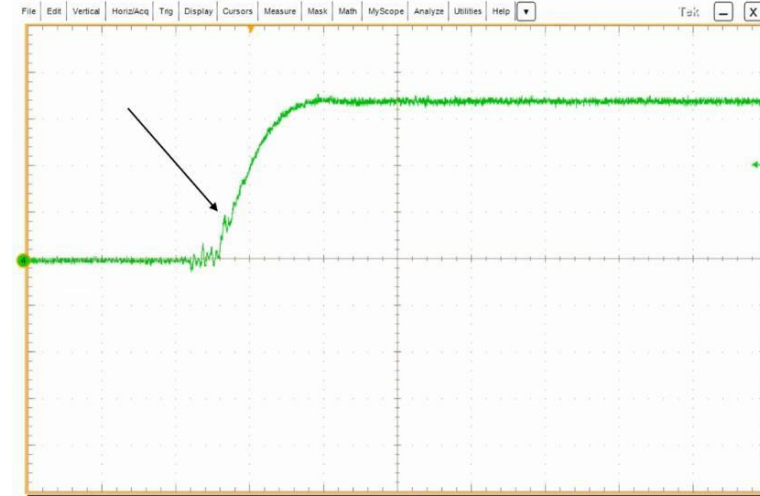
Figure 3: P2220 Input impedance

The importance of probing

GROUND LEAD INDUCTANCE

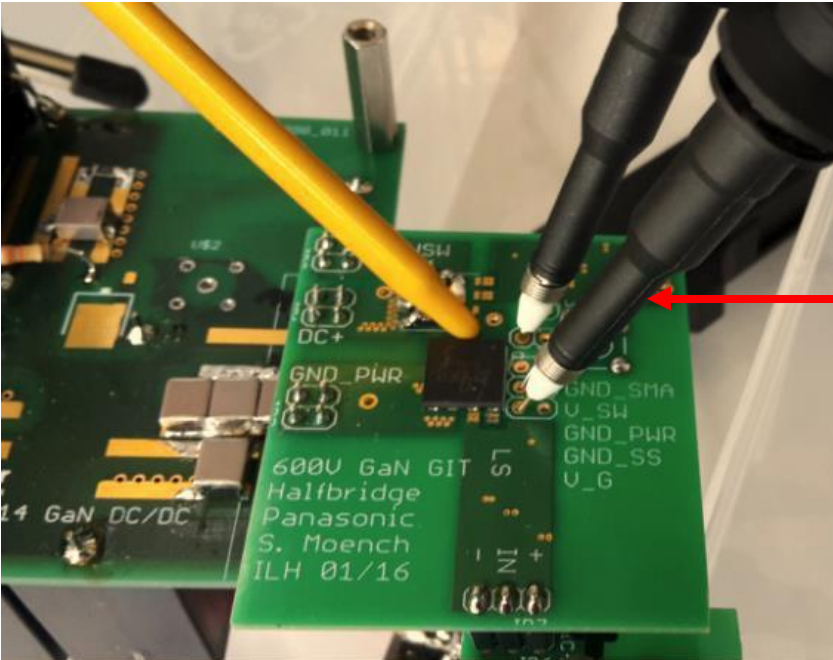


**Inductance + tip capacitance
resonate = ringing**

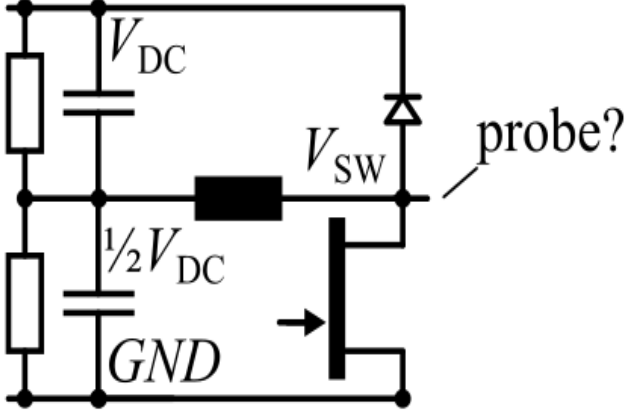


The importance of probing (low side)

Low Side V_{ds} requires high bandwidth and high voltage capabilities



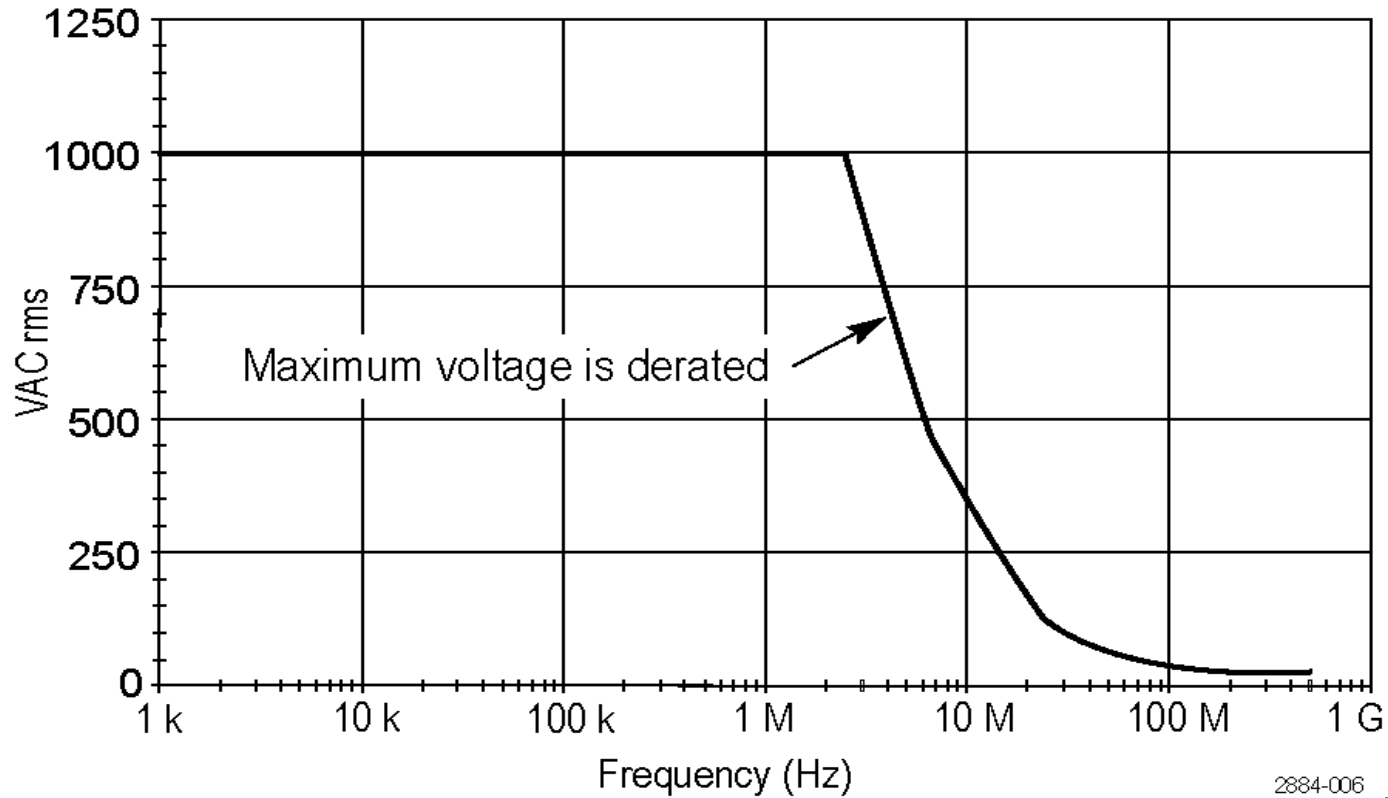
University of Stuttgart, Germany



The importance of probing

LOW SIDE MEASUREMENTS CONSIDERATIONS

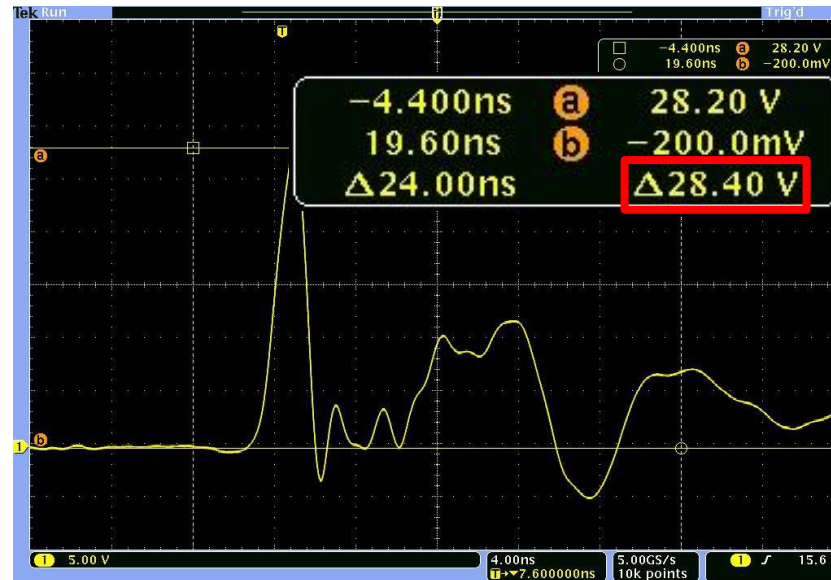
Beware of voltage derating vs frequency!



2884-006

The importance of probing

Differential probes are expensive: Why not float the oscilloscope and use passive probes?



Bad signal fidelity (capacitive coupling) and unsafe

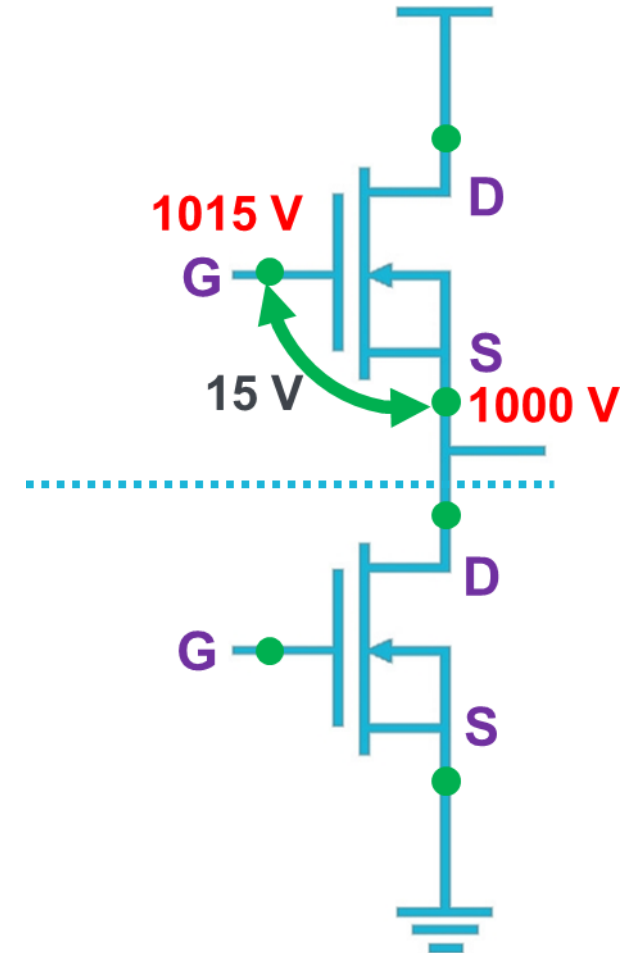
High side gate measurement comparison

The importance of probing

HIGH SIDE MEASUREMENTS CONSIDERATION

But high voltage differential probes have **downsides**

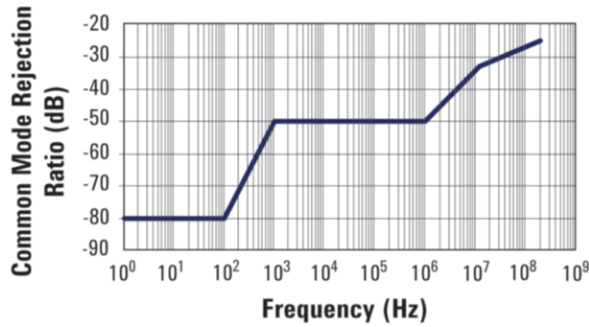
- High attenuation degrades signal to noise (High Side Vg)
- Radiated noise couples to the measurements through the leads
- Voltage derating vs frequency also applies
- **CMRR is insufficient**



The importance of probing

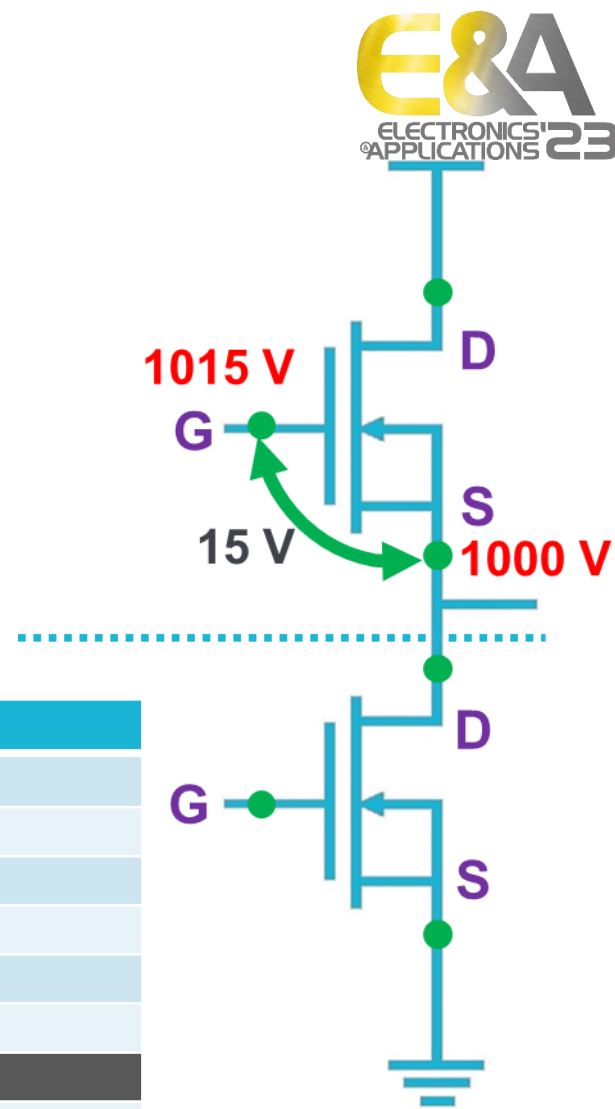
CMRR

← Exemple of CMRR derating curve



CM error at 100MHz: $1000V/22 = 45V$

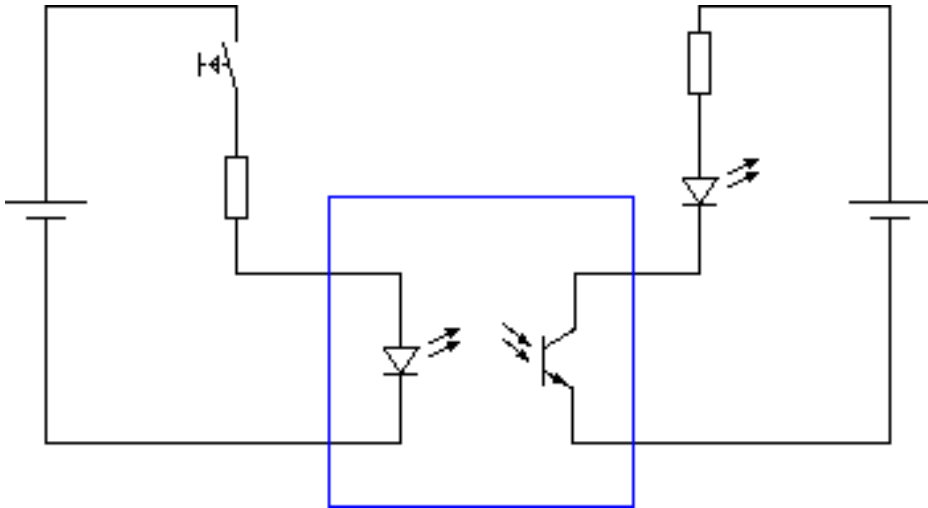
	High Voltage Differential
Bandwidth	X probe
CMRR DC	200 MHz
CMRR 1 MHz	>80 dB (10,000:1)
CMRR 100 MHz	50 dB (316:1)
CMRR Full Bandwidth	27 dB (22:1)
Common Mode Error (1kV) @ DC	15 dB (5.6:1)
Common Mode Error (1kV) @ 1 MHz	0.1 V
Common Mode Error (1kV) @ 100 MHz	3.2 V
Common Mode Error (1kV) @ Full BW	45.2 V
	178.6 V



The importance of probing

INTRODUCTION TO ISOLATED PROBES

An isolated probe uses galvanic (optical) isolation to divorce the reference voltage of the probe from the reference voltage of the oscilloscope

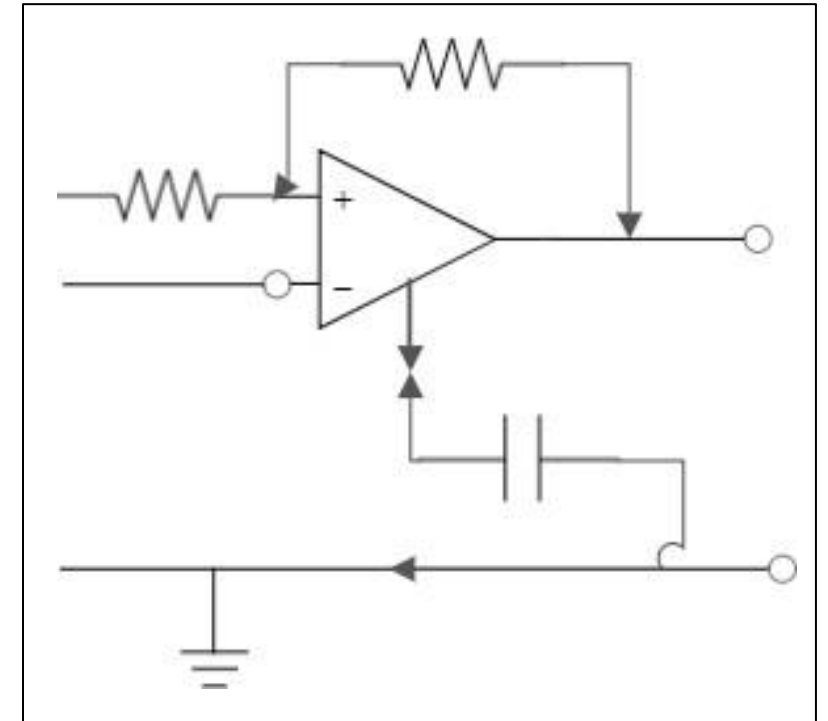
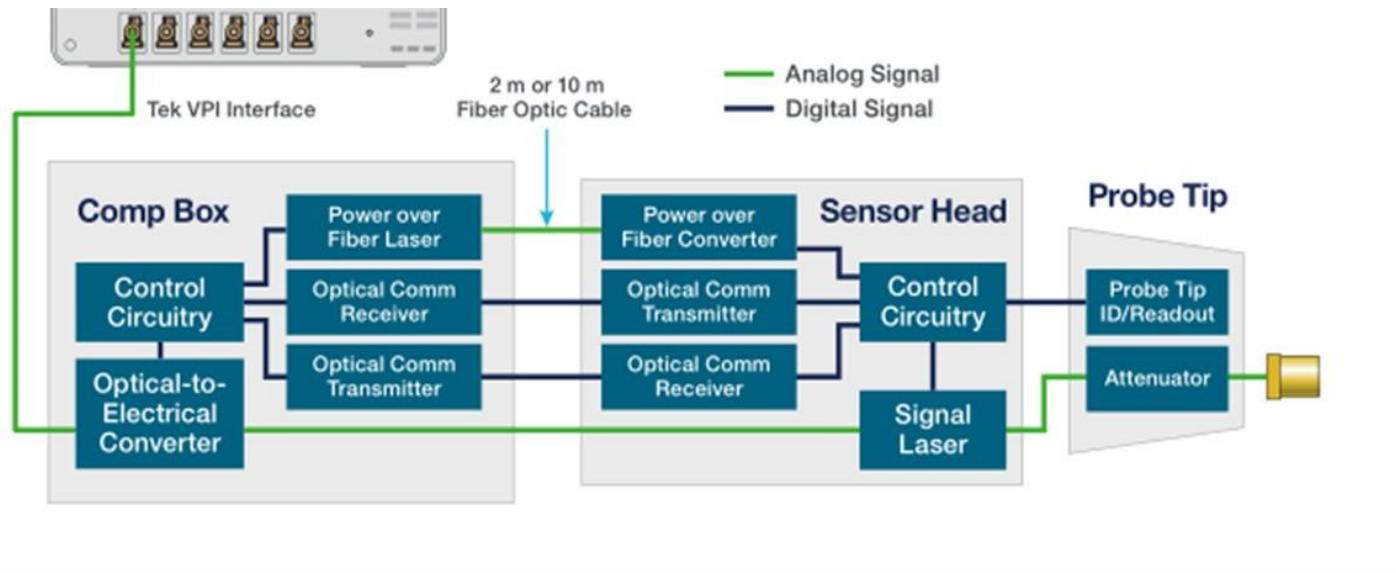


Advantages:

	Isolated Probe
EMI Susceptibility	Shielded Coaxial cable with common mode chokes; less coupling, less ringing
Cable Length	2m fiber optic cable, 10m cable option
Safety	Complete galvanic isolation allows scope to sit outside PVC chamber
Ground Loops	Eliminates ground loops
Loading	No input +to ground loading

The importance of probing

INTRODUCTION TO ISOLATED PROBES: NOTE ON ARCHITECTURE



The importance of probing

INTRODUCTION TO ISOLATED/Optical PROBES

Planned test points (MMCX Connectors) → Best Performance

MMCX connectors are small, **shielded**, inexpensive . They can be soldered onto unplanned test points.

CREE ⇄ Wolfspeed.

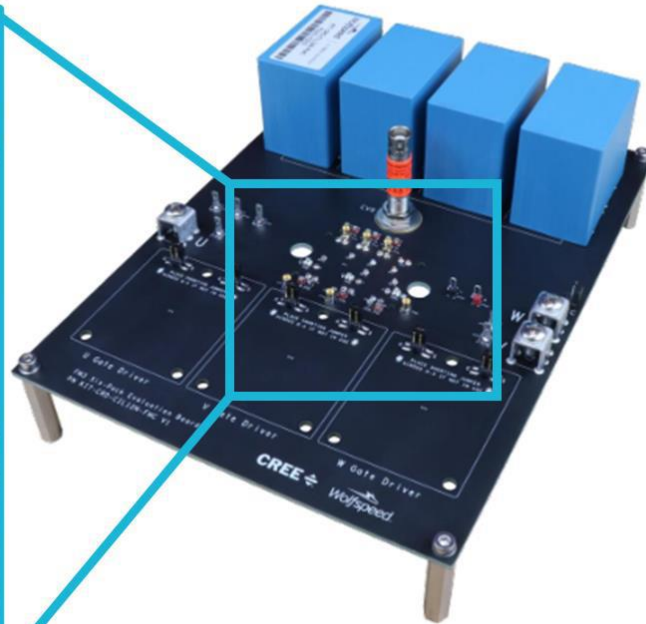


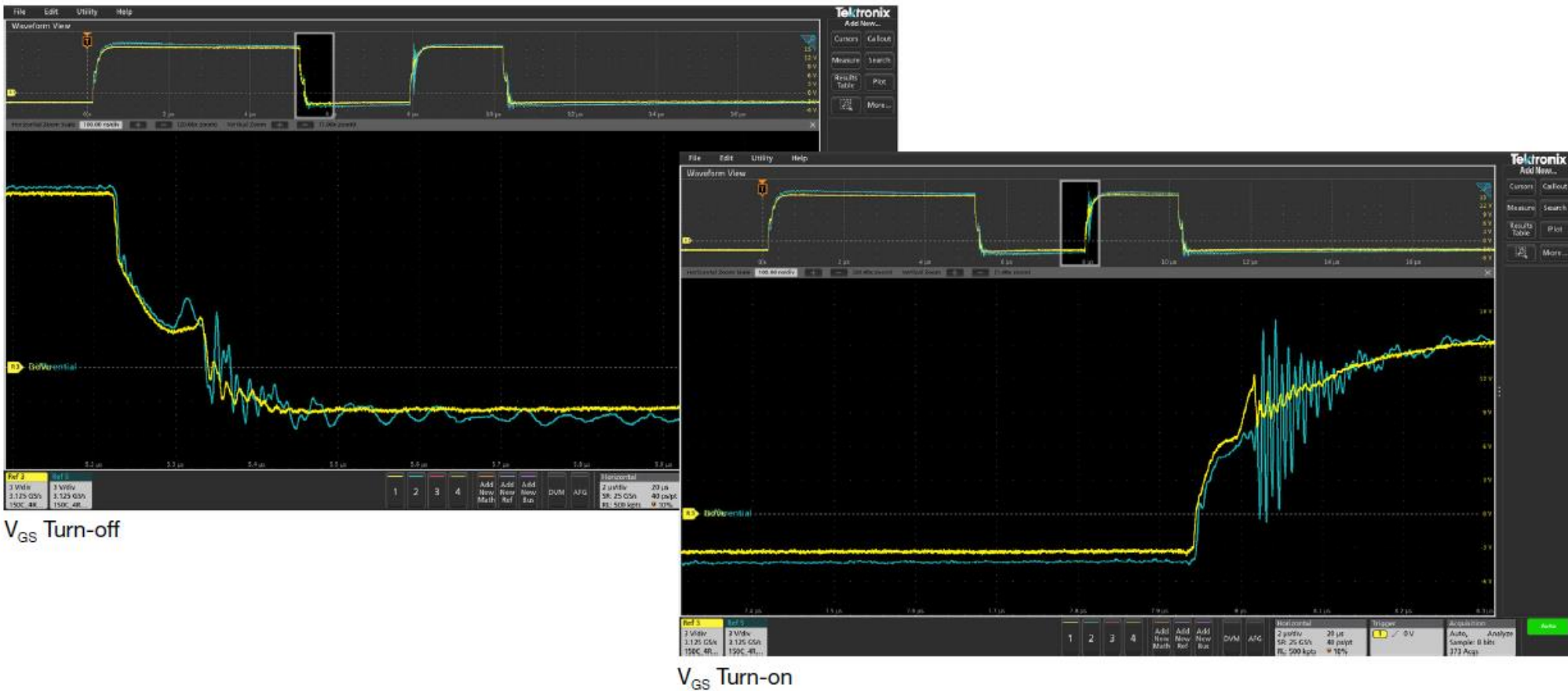
Figure 3. CIL Evaluation kit for FM3 Module



The importance of probing

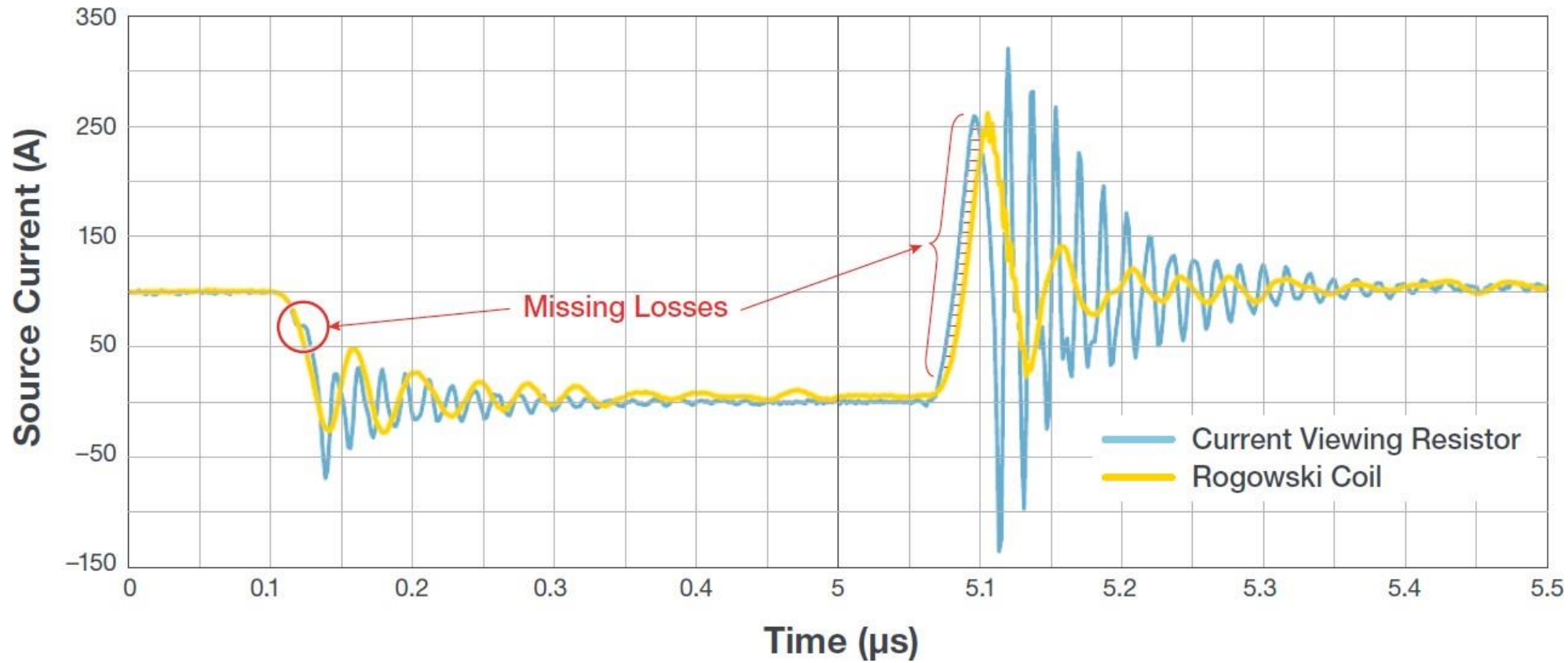
INTRODUCTION TO ISOLATED PROBES

High Side V_{GS} example-Differential Probe (blue trace) vs. Optically Isolated Probe (yellow trace).



The importance of probing

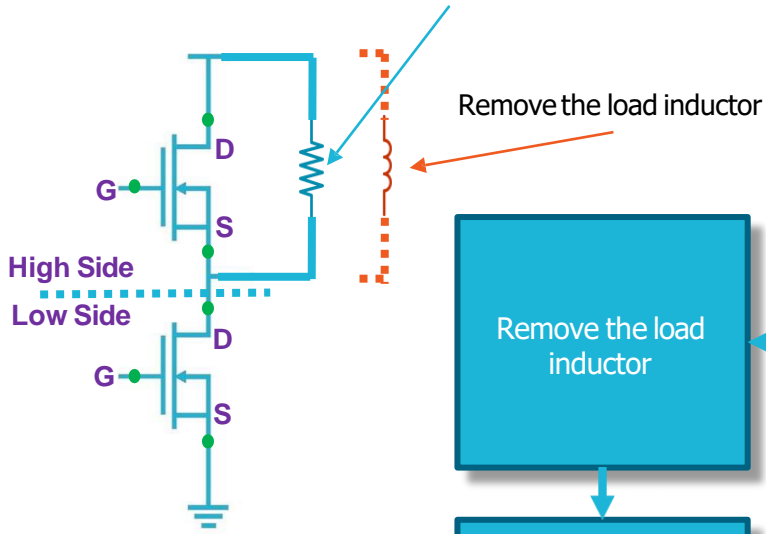
CURRENT MEASUREMENTS



CVR vs Rogowski Current Probe, CAB011M12FM3 ($T_J = 150^\circ\text{C}$, $R_G = 1\ \Omega$, $V_{DS} = 600\ \text{V}$, $I_S = 100\ \text{A}$).

Conventional Deskew Challenges

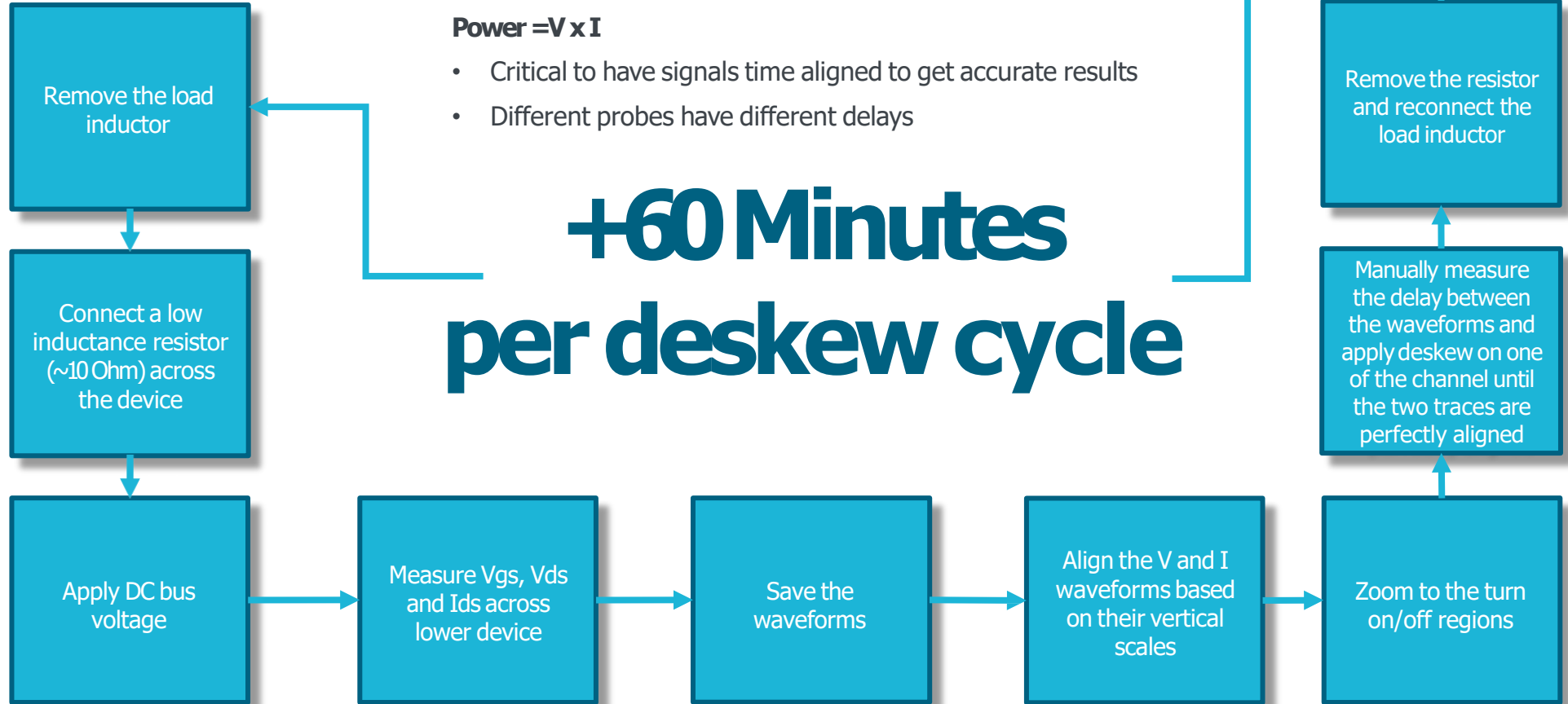
Insert a 5-10ohm Resistor



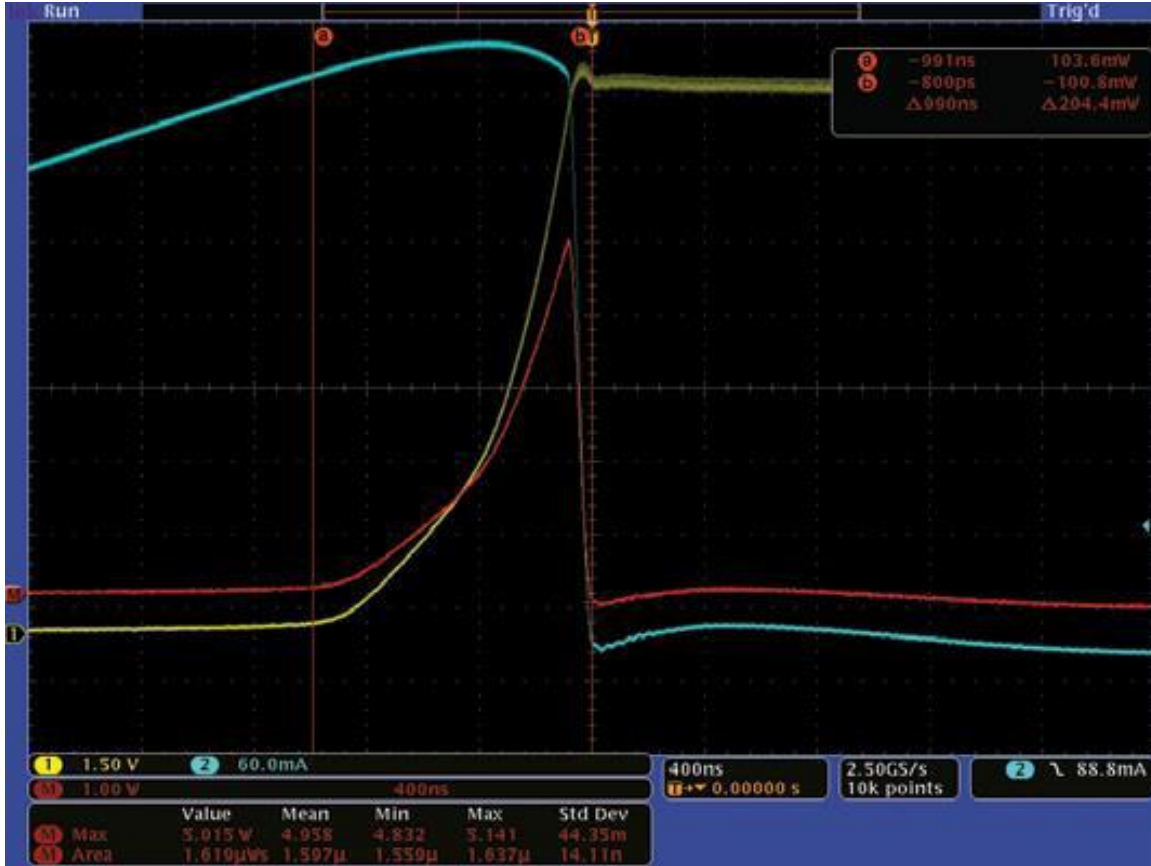
Power =V x I

- Critical to have signals time aligned to get accurate results
- Different probes have different delays

+60 Minutes
per deskew cycle



Deskew

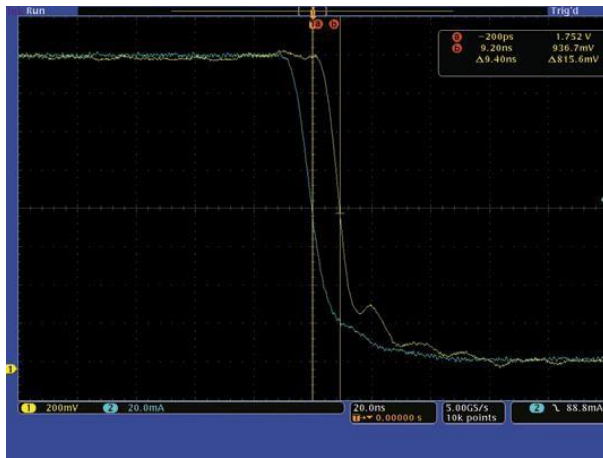


Switching loss **Mean power = 4.958 W**

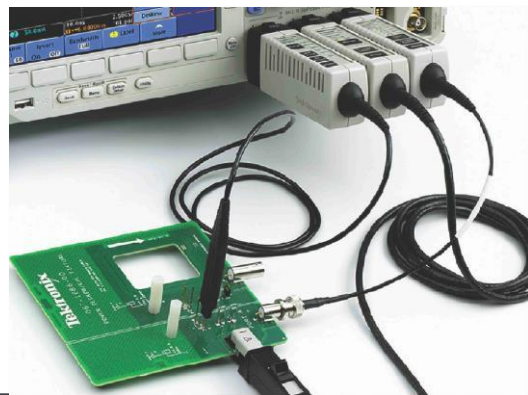
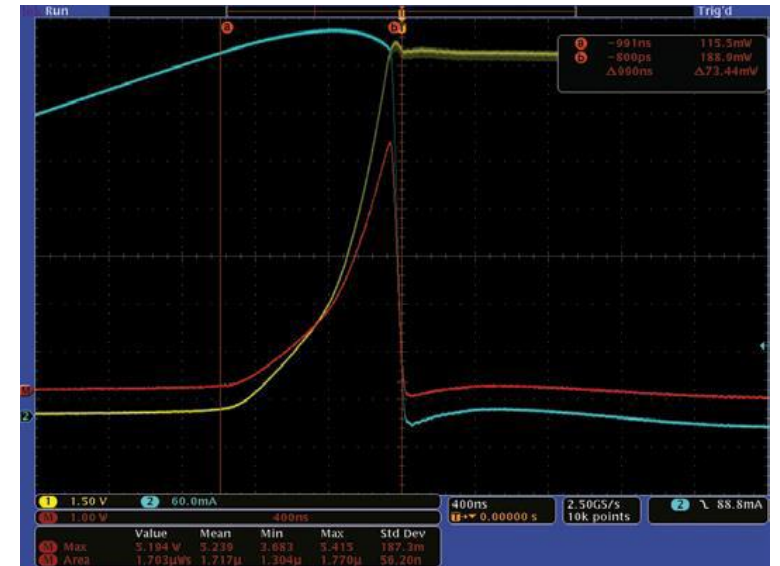
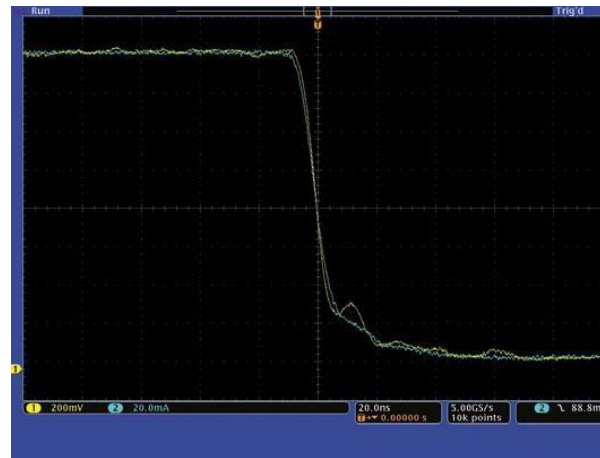
DESKEW

Mean power = **5.239 W**

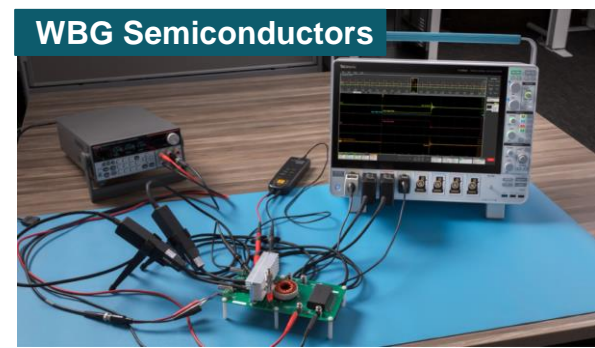
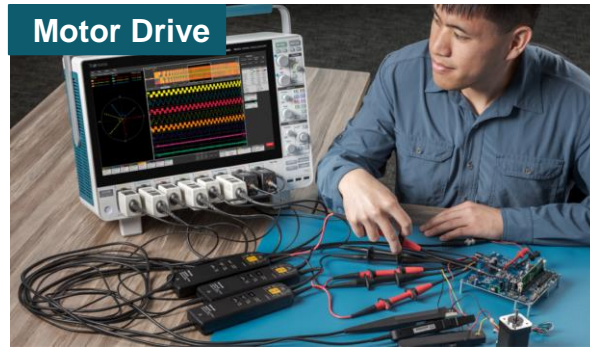
5.6% error w/o deskew



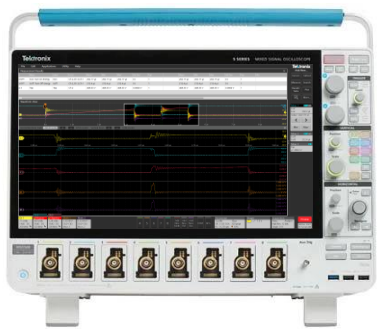
DESKEW



Complete Wide Bandgap Validation



SCOPE



5 SERIES B MSO

PROBES



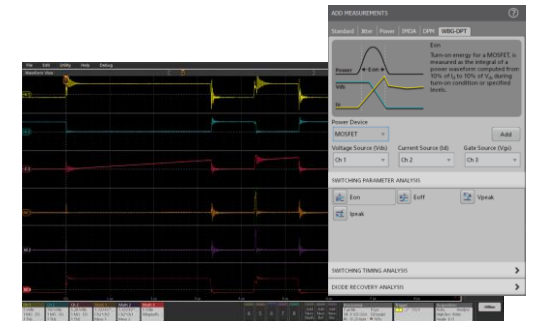
TCPx, TPPx, IsoVu

DC POWER GATE DRIVE



SMU, AFG

SOFTWARE



Opt. WBG-DPT

SERVICES

Total protection service options to protect your investment over the lifetime of the solution

SOFTWARE BUNDLES

Thank you ..